

Catalog # 03-0780 Lithium t-butoxide, 98+%

Li-O^tBu

Thermal Behavior:

- Melting point: 150°C
- Sublimation temperature: 110°C/0.75 Torr [1]
- Vapor pressure 0.1 Torr/120°C [2]
- TGA analysis is available in [3]

Technical Notes:

1. ALD precursor for Li thin film deposition widely used in Li ion battery related applications

| Target Deposit | Deposition Technique | Delivery Temperature | Pressure | Co-reactants | Deposition Temperature | Ref. |
|---|----------------------|----------------------|------------------|---|------------------------|------|
| Li ₂ O LiOH | ALD | 160°C | 0.2 Torr | H ₂ O, O ₂ ^{Plasma} | 225-300°C | 4 |
| Li ₂ S | ALD | 140°C | 0.2 Torr | H ₂ S | 150-300° | 5 |
| LiF | ALD | 135°C, 130°C | 1 Torr, 3.4 Torr | HF, NH ₄ F | 150-300°C | 6-7 |
| LiAlF ₄ | ALD | 160-170°C | - | AlCl ₃ , TiF ₄ | 250°C | 8 |
| LiTa _x O _y | ALD | 170°C | - | Ta(OEt) ₅ , H ₂ O | 225°C | 9 |
| LiCoO ₂ | ALD | 150°C | 0.02 Torr | CoCp ₂ , O ₂ ^{Plasma} | 325°C | 10 |
| LiFePO ₄ | ALD | 180°C | - | FeCp ₂ , P(OMe) ₃ O, H ₂ O/O ₃ | 300°C | 11 |
| LiPON | ALD | 165°C | 0.2 Torr | P(OMe) ₃ O, H ₂ O; N ₂ ^{Plasma} | 250°C | 12 |
| Li ₇ La ₃ Zr ₂ O ₁₂ | ALD | 170°C | - | La(PrFMD) ₃ , Zr(NMe ₂) ₄ , H ₂ O/O ₃ | 225°C, 555°C | 13 |
| LiMn _x O _y | ALD | 160°C | - | Mn(thd) ₃ , H ₂ O/O ₃ | 225°C | 14 |

References:

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